General Purpose Transistor

NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-323/SC-70 package which is designed for low power surface mount applications.

Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector – Base Voltage	V _{CBO}	75	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	Ι _C	600	mAdc

THERMAL CHARACTERISTICS

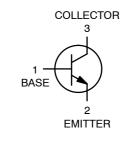
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board $T_A = 25^{\circ}C$	PD	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



P1 = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT2222AWT1G	SC–70 (Pb–Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Charac	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS		·				
Collector – Emitter Breakdown Voltage (Note $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	1)	V _(BR) CEO	40	-	Vdc	
Collector – Base Breakdown Voltage ($I_C = 10 \ \mu Adc, \ I_E = 0$)		V _{(BR)CBO}	75	-	Vdc	
Emitter – Base Breakdown Voltage ($I_E = 10 \ \mu Adc, \ I_C = 0$)		V _{(BR)EBO}	6.0	-	Vdc	
Base Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc)		I _{BL}	-	20	nAdc	
Collector Cutoff Current (V_{CE} = 60 Vdc, V_{EB} = 3.0 Vdc)		ICEX	-	10	nAdc	
ON CHARACTERISTICS (Note 1)			-			
$ \begin{array}{l} \text{DC Current Gain (Note 1)} \\ (I_{C} = 0.1 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_{C} = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_{C} = 150 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_{C} = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \end{array} $		H _{FE}	35 50 75 100 40	- - 300 -	-	
))	V _{CE(sat)}		0.3 1.0	Vdc	
$\begin{array}{l} \text{Base}-\text{Emitter Saturation Voltage (Note 1)} \\ (I_{C}=150 \text{ mAdc}, I_{B}=15 \text{ mAdc}) \\ (I_{C}=500 \text{ mAdc}, I_{B}=50 \text{ mAdc}) \end{array}$		V _{BE(sat)}	0.6 _	1.2 2.0	Vdc	
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product ($I_C = 20$ mAdc, $V_{CE} = 20$ Vdc, f = 100 MH	lz)	fT	300	-	MHz	
Output Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$		C _{obo}	-	8.0	pF	
Input Capacitance (V _{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz)		C _{ibo}	-	30	pF	
Input Impedance (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kHz)	h _{ie}	0.25	1.25	kΩ	
Voltage Feedback Ratio (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kHz)	h _{re}	-	4.0	X 10-'	
Small – Signal Current Gain (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kHz)	h _{fe}	75	375	-	
Output Admittance (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kHz)	h _{oe}	25	200	μmhos	
Noise Figure (V _{CE} = 10 Vdc, I _C = 100 μ Adc, R _S = 1.0 k	:Ω, f = 1.0 kHz)	NF	-	4.0	dB	
SWITCHING CHARACTERISTICS		·	•	•	•	
Delay Time	$(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc},$	t _d	-	10		
Rise Time	$I_{\rm C} = 150 \text{ mAdc}, I_{\rm B1} = 15 \text{ mAdc})$	t _r	-	25	ns	
Storage Time	$(V_{CC} = 30 \text{ Vdc}, I_{C} = 150 \text{ mAdc},$	t _s	-	225	ns	
Fall Time	I _{B1} = I _{B2} = 15 mAdc)	t _f	-	60		

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS

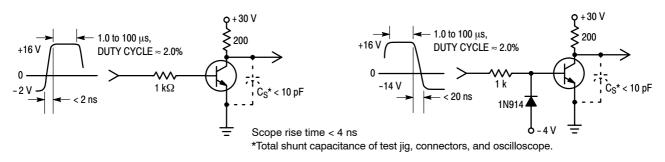
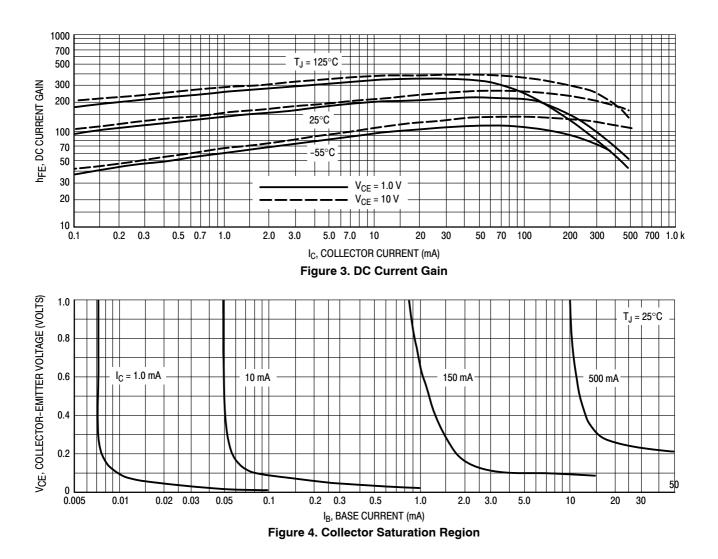




Figure 2. Turn-Off Time



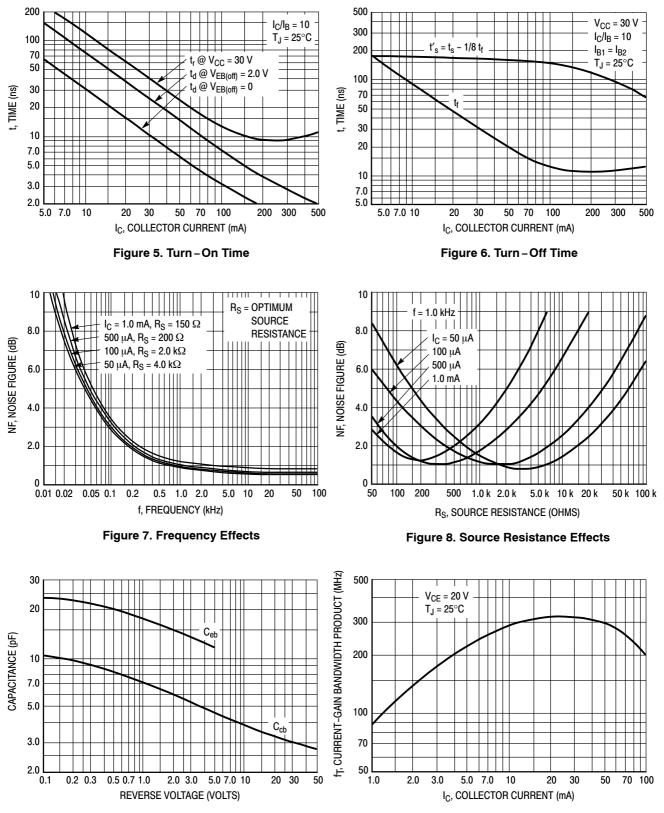
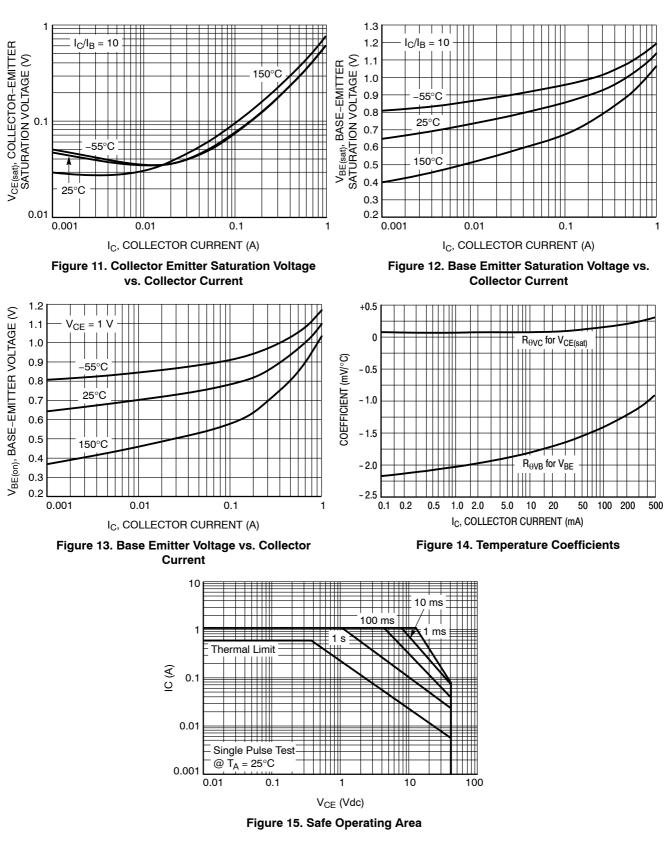


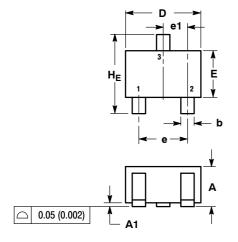
Figure 9. Capacitances

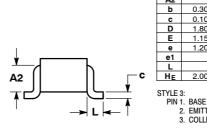
Figure 10. Current–Gain Bandwidth Product



PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 **ISSUE M**





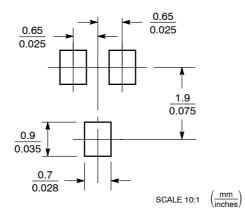
NOTES DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.

2. EMITTER

3. COLLECTOR

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.7 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
Ш	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.425 REF			0.017 REF		
HE	2.00	2.10	2.40	0.079	0.083	0.095

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILC does not convey any license under its patent rights or the rights of others. SCILC products are not designed, intended, or authorized for use a components in systems intended for surgical implant into the body, or other applications. bit intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative